# **Dual General Purpose Transistor**

The NST3904DXV6T1 device is a spin-off of our popular SOT-23/SOT-323 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-563 six-leaded surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

#### **Features**

- h<sub>FE</sub>, 100-300
- Low  $V_{CE(sat)}$ ,  $\leq 0.4 \text{ V}$
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- These are Pb-Free Devices

## **MAXIMUM RATINGS**

Rating		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CEO</sub>	40	Vdc
Collector - Base Voltage		V <sub>CBO</sub>	60	Vdc
Emitter - Base Voltage		V <sub>EBO</sub>	6.0	Vdc
Collector Current - Continuous		I <sub>C</sub>	200	mAdc
Electrostatic Discharge	HBM MM	ESD	>16000 >2000	V

### THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C (Note 1)	P <sub>D</sub>	357 2.9	mW mW/°C
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\theta JA}$	350	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C (Note 1)	P <sub>D</sub>	500 4.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	250	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

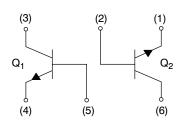
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-4 @ Minimum Pad



## ON Semiconductor®

http://onsemi.com



NST3904DXV6T1



SOT-563 CASE 463A PLASTIC

#### **MARKING DIAGRAM**



MA = Device Code M = Date Code

= Pb-Free Package(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NST3904DXV6T1	SOT-563*	4000/Tape & Reel
NST3904DXV6T1G	SOT-563*	4000/Tape & Reel
NST3904DXV6T5	SOT-563*	8000/Tape & Reel
NST3904DXV6T5G	SOT-563*	8000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>This package is inherently Pb-Free.

## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_{A} = 25^{\circ}\text{C unless otherwise noted})$

	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS		1	•			
Collector - Emitter Breakdown	voltage (Note 2) (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	40	_	Vdc	
Collector - Base Breakdown \	V <sub>(BR)CBO</sub>	60	-	Vdc		
Emitter - Base Breakdown Vo	ltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	6.0	-	Vdc	
Base Cutoff Current (V <sub>CE</sub> = 3	0 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>BL</sub>	-	50	nAdc	
Collector Cutoff Current (V <sub>CE</sub>	= 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>CEX</sub>	-	50	nAdc	
ON CHARACTERISTICS (No	te 2)		•		1	
$\begin{array}{l} \text{DC Current Gain} \\ \text{(I}_{\text{C}} = 0.1 \text{ mAdc, V}_{\text{CE}} = 1.0 \\ \text{(I}_{\text{C}} = 1.0 \text{ mAdc, V}_{\text{CE}} = 1.0 \\ \text{(I}_{\text{C}} = 10 \text{ mAdc, V}_{\text{CE}} = 1.0 \\ \text{(I}_{\text{C}} = 50 \text{ mAdc, V}_{\text{CE}} = 1.0 \\ \text{(I}_{\text{C}} = 100 \text{ mAdc, V}_{\text{CE}} = 1.0 \end{array}$	Vdc) Vdc) Vdc)	h <sub>FE</sub>	40 70 100 60 30	- 300 - -	-	
Collector – Emitter Saturation ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mag}$ ) ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mag}$ )	V <sub>CE(sat)</sub>		0.2 0.3	Vdc		
Base – Emitter Saturation Volt ( $I_C = 10 \text{ mAdc}$ , $I_B = 1.0 \text{ mag}$ ( $I_C = 50 \text{ mAdc}$ , $I_B = 5.0 \text{ mag}$	V <sub>BE(sat)</sub>	0.65	0.85 0.95	Vdc		
SMALL-SIGNAL CHARACT	ERISTICS	•		•		
Current - Gain - Bandwidth P	roduct (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	f <sub>T</sub>	300	_	MHz	
Output Capacitance (V <sub>CB</sub> = 5	C <sub>obo</sub>	-	4.0	pF		
Input Capacitance (V <sub>EB</sub> = 0.5	Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ibo</sub>	-	8.0	pF	
Input Impedance (V <sub>CE</sub> = 10 V	h <sub>ie</sub>	1.0 2.0	10 12	kΩ		
Voltage Feedback Ratio (V <sub>CE</sub>	h <sub>re</sub>	0.5 0.1	8.0 10	X 10 <sup>-4</sup>		
Small - Signal Current Gain (\	h <sub>fe</sub>	100 100	400 400	-		
Output Admittance (V <sub>CE</sub> = 10	h <sub>oe</sub>	1.0 3.0	40 60	μmhos		
Noise Figure (V <sub>CE</sub> = 5.0 Vdc,	NF		5.0 4.0	dB		
SWITCHING CHARACTERIS	TICS		•	•		
Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc})$	t <sub>d</sub>	-	35	ns	
Rise Time	(I <sub>C</sub> = 10 mAdc, I <sub>B1</sub> = 1.0 mAdc)	t <sub>r</sub>	-	35		
Storage Time	(V <sub>CC</sub> = 3.0 Vdc, I <sub>C</sub> = 10 mAdc)	t <sub>s</sub>	-	200		
Fall Time	$(I_{B1} = I_{B2} = 1.0 \text{ mAdc})$	t <sub>f</sub>	-	50	ns	

<sup>2.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s; Duty Cycle  $\leq$  2.0%.

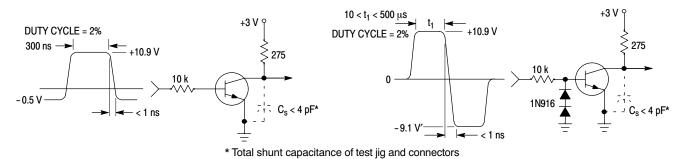


Figure 1. Delay and Rise Time Equivalent Test Circuit

Figure 2. Storage and Fall Time Equivalent Test Circuit

## TYPICAL TRANSIENT CHARACTERISTICS

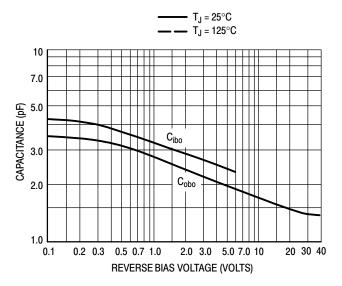


Figure 3. Capacitance

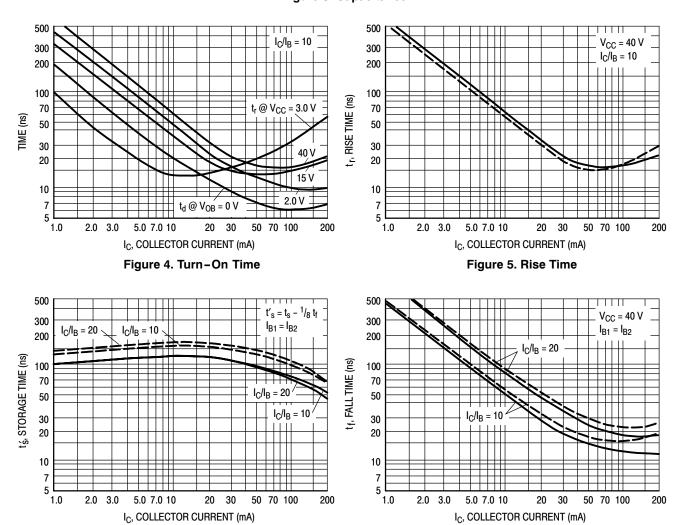
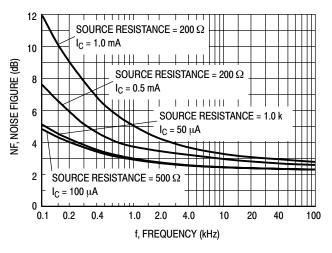


Figure 6. Storage Time

Figure 7. Fall Time

# TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$ 



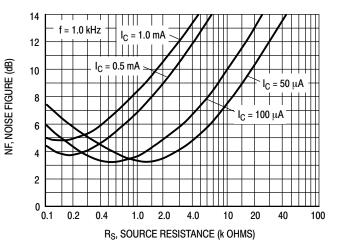
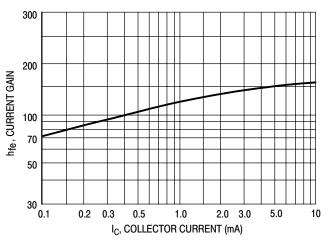


Figure 8. Noise Figure

Figure 9. Noise Figure

## **h PARAMETERS**

 $(V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$ 



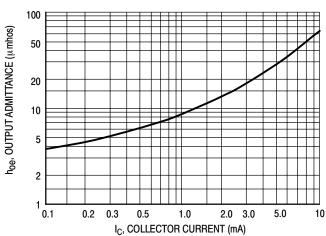


Figure 10. Current Gain

1.0 2.0 2.0 0.7 0.5 0.1 0.2 0.3 0.5 1.0 2.0 3.0 5.0 10

Figure 11. Output Admittance

Figure 12. Input Impedance

Figure 13. Voltage Feedback Ratio

IC, COLLECTOR CURRENT (mA)

, VOLTAGE FEEDBACK RATIO (x 10 -4

## **TYPICAL STATIC CHARACTERISTICS**

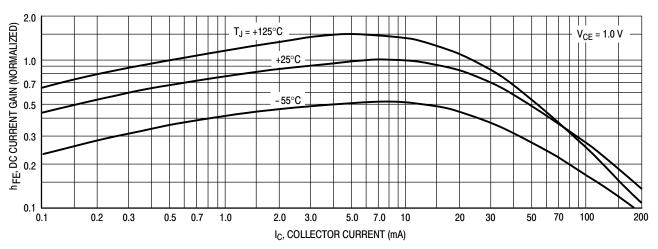


Figure 14. DC Current Gain

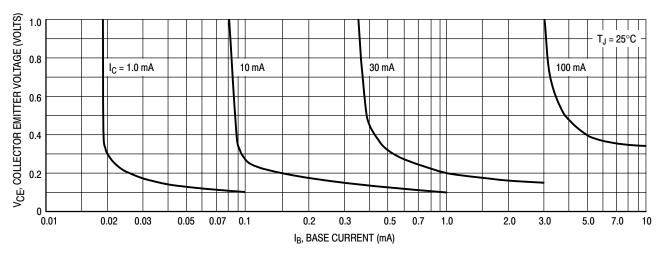


Figure 15. Collector Saturation Region

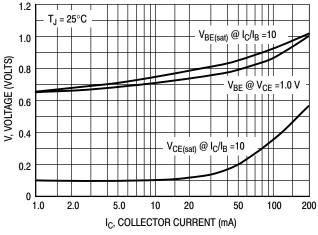
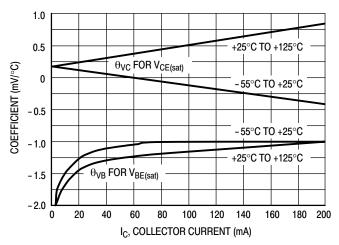


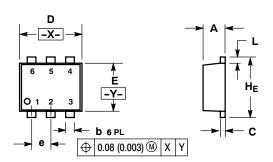
Figure 16. "ON" Voltages



**Figure 17. Temperature Coefficients** 

#### PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A-01 ISSUE F

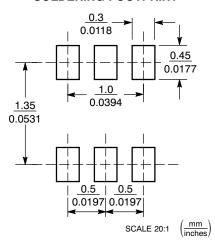


#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
E	1.10	1.20	1.30	0.043	0.047	0.051
е	0.5 BSC		0.02 BSC			
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.062	0.066

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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